

# Midium Power Transistors (80V / 1.5A)

## **2SCR554P**

#### Structure

NPN Silicon epitaxial planar transistor

#### Features

- 1) Low saturation voltage, typically  $V_{CE \; (sat)} = 0.3 V \; (Max.) \; (I_C \; / \; I_B = 500 mA \; / \; 25 mA)$
- 2) High speed switching

#### Applications

Driver

#### Packaging specifications

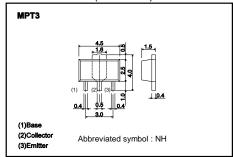
| Type     | Package                      | Taping |
|----------|------------------------------|--------|
|          | Code                         | T100   |
|          | Basic ordering unit (pieces) | 1000   |
| 2SCR554P |                              | 0      |

#### ● Absolute maximum ratings (Ta = 25°C)

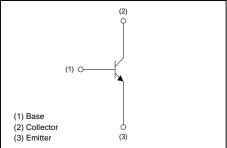
| Para                         | Symbol | Limits             | Unit       |    |
|------------------------------|--------|--------------------|------------|----|
| Collector-base voltage       |        | $V_{CBO}$          | 80         | V  |
| Collector-emitter voltage    |        | $V_{CEO}$          | 80         | V  |
| Emitter-base voltage         |        | $V_{EBO}$          | 6          | V  |
| Collector current            | DC     | Ic                 | 1.5        | Α  |
|                              | Pulsed | I <sub>CP</sub> *1 | 3          | Α  |
| Power dissipation            |        | P <sub>D</sub> *2  | 0.5        | W  |
|                              |        | P <sub>D</sub> *3  | 2          | W  |
| Junction temperature         |        | T <sub>j</sub>     | 150        | °C |
| Range of storage temperature |        | T <sub>stg</sub>   | -55 to 150 | °C |

<sup>\*1</sup> Pw=10ms, Single Pulse

#### • Dimensions (Unit : mm)



● Inner circuit (Unit : mm)



<sup>\*2</sup> Each terminal mounted on a recommended land.

<sup>\*3</sup> Mounted on a ceramic board. (40x40x0.7mm³)

2SCR554P Data Sheet

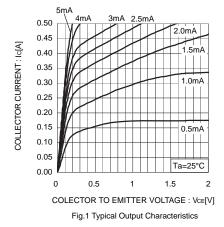
# ●Electrical characteristic (Ta = 25°C)

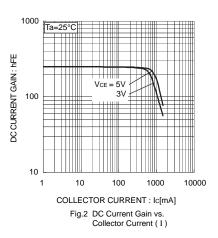
| Parameter                             | Symbol                          | Min. | Тур. | Max. | Unit | Conditions  |  |
|---------------------------------------|---------------------------------|------|------|------|------|---|--|
| Collector-emitter breakdown voltage   | $BV_{CEO}$                      | 80   | -    | -    | V    | I <sub>C</sub> = 1mA  |  |
| Collector-base breakdown voltage      | BV <sub>CBO</sub>               | 80   | -    | -    | V    | I <sub>C</sub> = 100μΑ  |  |
| Emitter-base breakdown voltage        | $BV_{EBO}$                      | 6    | -    | -    | V    | I <sub>E</sub> = 100μΑ  |  |
| Collector cut-off current             | I <sub>CBO</sub>                | -    | -    | 1    | μА   | V <sub>CB</sub> = 80V   |  |
| Emitter cut-off current               | I <sub>EBO</sub>                | -    | -    | 1    | μА   | V <sub>EB</sub> = 4V  |  |
| Collector-emitter staturation voltage | $V_{CE(sat)}$                   | -    | 100  | 300  | mV   | $I_{C}$ = -500mA, $I_{B}$ = 25mA                                    |  |
| DC current gain                       | h <sub>FE</sub>                 | 120  | -    | 390  | -    | $V_{CE}$ = 3V, $I_{C}$ = 100mA                                      |  |
| Transition frequency                  | f⊤                              | -    | 300  | -    | MHz  | V <sub>CE</sub> = 10V<br>I <sub>E</sub> =-200mA, f=100MHz           |  |
| Collector output capacitance          | C <sub>ob</sub>                 | -    | 10   | -    | pF   | V <sub>CB</sub> = 10V, I <sub>E</sub> =0A<br>f=1MH z                |  |
| Turn-on time                          | t <sub>on</sub> * <sub>1</sub>  | -    | 50   | -    | ns   | 1 0 7 A 1 70 m A  |  |
| Storage time                          | t <sub>stg</sub> * <sub>1</sub> | -    | 600  | -    | ns   | $I_{C}$ = 0.7A, $I_{B1}$ = 70mA,<br>$I_{B2}$ =-70mA, $V_{CC}$ ~ 10V |  |
| Fall time                             | t <sub>f</sub> *1               | -    | 60   | -    | ns   | 182-701171, 700-107   |  |

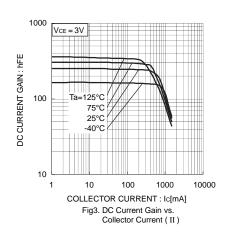
<sup>\*1</sup> See switching time test circuit

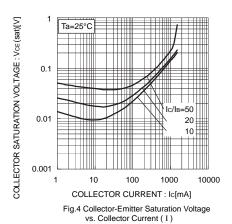
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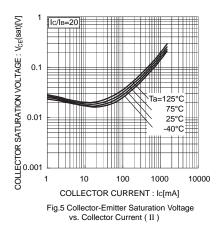
#### •Electrical characteristic curves

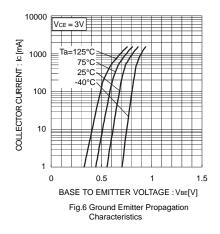


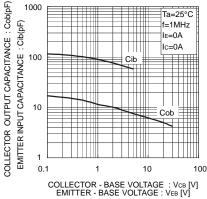












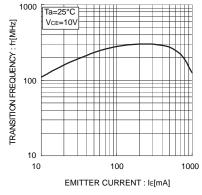


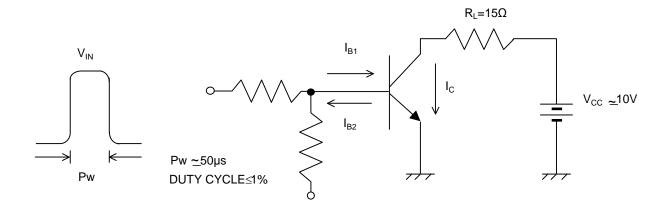
Fig.7 Emitter Input Capacitance vs. Emitter-Base Voltage Collector Output Capacitance vs. Collector-Base Voltage

Fig.8 Gain Bandwidth Product vs. Emitter Current

Fig.9 Safe Operating Area

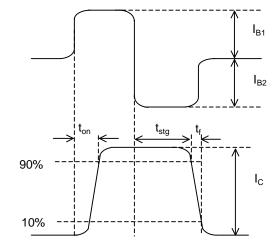
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## •Switching time test circuit



BASE CURENT WAVEFORM

COLLECTOR CURRENT WAVEFORM



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